

**BOE MODEL NO :JH123N00500**

---

## 1. GENERAL DESCRIPTION

### 1.1 DESCRIPTION

JH123N00500 is a transmissive type color active matrix TFT (Thin Film Transistor) liquid crystal display (LCD) that uses amorphous silicon TFT as a switching device. This model is composed of a TFT-LCD module (TFT-LCD panel, driver IC and FPC), a back-light unit and. The resolution of 720\*1920 pixels and can display up to 16.7M colors.

### 1.2 GENERAL INFORMATION

Items	Specification	Unit	Note
Display mode	Normally Black	-	-
LCM outline size	310.00(L) x 128.00(W) x 6.2(T)	mm	Note (1)(2)
Active area	109.512 (H) x 292.032 (V)	mm	-
Number of pixels	720*1920	pixels	-
Pixel arrangement	RGB stripe	-	-
Display color	16.7M	color	-
Viewing direction	ALL	-	-
Controller / Driver	HX83102E	-	-
Data interface	MIPI-4L	-	-
Backlight	6 White LEDs In Series 8 Parallels	-	-
Weight	TBD	g	-

Notes:

- (1) Touch panel and back-light unit are included.
- (2) FPC no included. (Refer to the module outline dimension for further information). Please see module specification drawing in Page14 for more details.

## 2. ELECTRICAL CHARACTERISTICS

### 2.1 LCM DC CHARACTERISTICS

(Ta=25±2°C)

Characteristics	Symbol	Min.	Typ.	Max.	Unit	Note
Power Supply Voltage 1		-		-	V	
Power Supply Voltage 2	IOVCC	-	1.8	-	V	
Power Supply Voltage 3	AVDD-	9	10.4	12	V	
Power Supply Voltage 4	-	-	-	-	V	
Power Supply Voltage 5	-	-	-	-	V	
Current Consumption	I <sub>DD</sub>	-	40	-	mA	Normal mode
	I <sub>DD-SLEEP</sub>		2		mA	Sleep mode
Input voltage "L" Level	V <sub>IL</sub>	GND	-	0.3VDD1	V	DVDD=3.0~3.6
Input voltage "H" Level	V <sub>IH</sub>	0.7VDD1	-	VDD1	V	
Output voltage "L" Level	V <sub>oL</sub>	0	-	0.2VDD1	V	I <sub>oL</sub> =1mA
Output voltage "H" Level	V <sub>oH</sub>	0.8VDD1	-	VDD1	V	I <sub>oH</sub> =-1mA

### 2.2 BACK-LIGHT UNIT CHARACTERISTICS

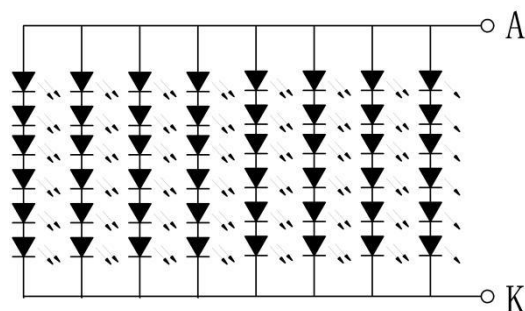
The back-light system is an edge-lighting type with 48 white LEDs. The characteristics of the back-light are shown in the following tables.

(Ta=25±2°C)

Characteristics	Symbol	Condition	Min.	Type	Max.	Unit	Notes
Forward Voltage	V <sub>f</sub>	I <sub>L</sub> =170mA	-	18	-	V	-
LED life time	-	I <sub>L</sub> =170mA	20,000	30,000	--	Hr	Note 1

Note:

- (1) The "LED life time" is defined as the module brightness decrease to 50% of original brightness at I<sub>L</sub>=170mA. The LED life time could be decreased if operating I<sub>L</sub> is larger than 170mA.



Backlight circuit diagram shown in below:

### 3. OPTICAL CHARACTERISTICS

The following items are measured under stable conditions. The optical characteristics should be measured in a dark room.

Measuring equipment: BM-5AS, BM-7, EZ-Contrast.

(Ta=25±2°C)

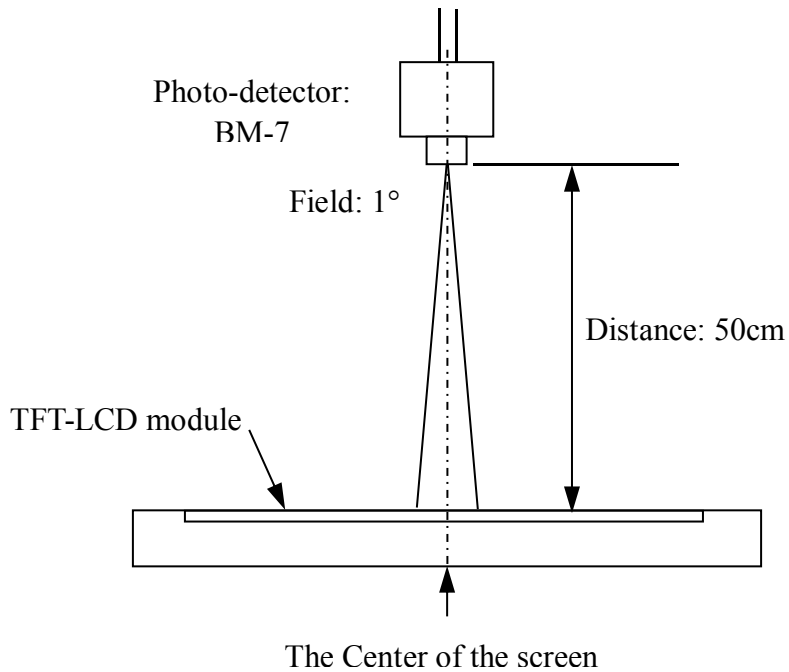
Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit	Note
Contrast Ratio (Center point)		C/R	-	800	1200	-	-	BM-7 Note(2)
Luminance of white (Center point)		L <sub>w</sub>	B/L on	-	<b>600</b>	-	cd/m <sup>2</sup>	BM-7
Luminance uniformity		U <sub>w</sub>	θ = 0. Normal viewing angle B/L On  Note(1)	80	-	-	%	BM-7 Note(3)
Response Time		Tr + Tf		-	45	-	ms	BM-5AS Note(4)
Color Chromaticity (CIE 1931)	White	W <sub>x</sub>	θ = 0. Normal viewing angle B/L On  Note(1)	-0.02	0.295	+0.02	-	BM-7 Note(5)
		W <sub>y</sub>		-0.02	0.314	+0.02		
	Red	R <sub>x</sub>		-0.02	0.641	+0.02		
		R <sub>y</sub>		-0.02	0.323	+0.02		
	Green	G <sub>x</sub>		-0.02	0.294	+0.02		
		G <sub>y</sub>		-0.02	0.599	+0.02		
	Blue	B <sub>x</sub>		-0.02	0.148	+0.02		
		B <sub>y</sub>		-0.02	0.067	+0.02		
Viewing Angle	Hor.	θ <sub>L</sub>	C/R≥10	-	85	-	Deg	EZ Contrast Note(6)
		θ <sub>R</sub>		-	85	-		
	Ver.	θ <sub>u</sub>		-	85	-		
		θ <sub>D</sub>		-	85	-		
Optima View Direction			ALL				Note(7)	

\* This condition will be changed by the evaluation circumstance. If product is exposed to high temperatures for extended time, there is a possibility of the polarizer film damage which could degrade the optical characteristics.

Notes:

- (1) Test Equipment Setup: After stabilizing and leaving the panel alone at a given temperature for 30min, the measurement should be executed. Measurement should be executed in a stable,

windless, and dark room 30min after lighting the back-light. This should be measured in the center of screen.

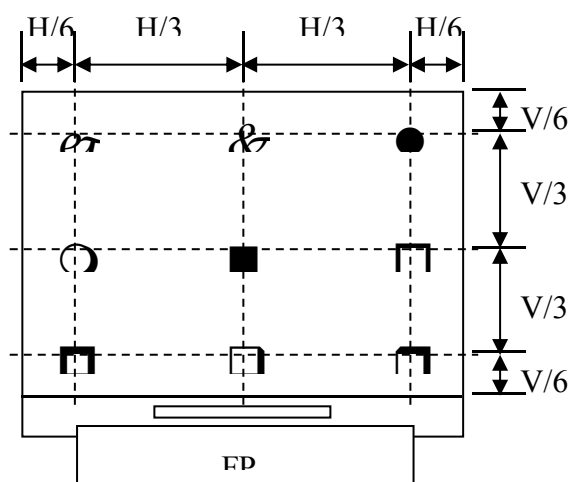


(2) Definition of Contrast Ratio (CR):

$$\text{Contrast Ratio (CR)} = \frac{\text{Luminance measured when LCD on the "white" state}}{\text{Luminance measured when LCD on the "black" state}}$$

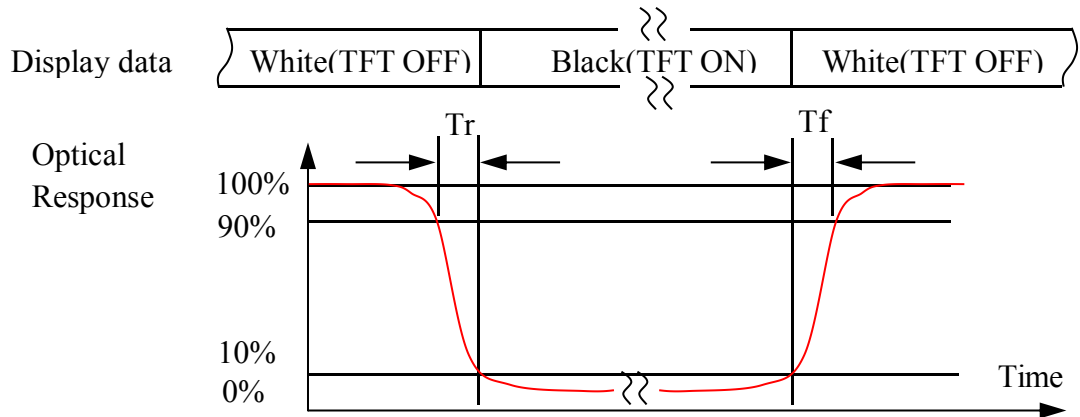
(3) Definition of Luminance Uniformity: Active area is divided into 9 measuring areas (Shown in below), every measuring point is placed at the center of each measuring area.

$$\text{Luminance Uniformity} = \frac{\text{Min Luminance of white among 9-points}}{\text{Max Luminance of white among 9-points}} \times 100\%$$

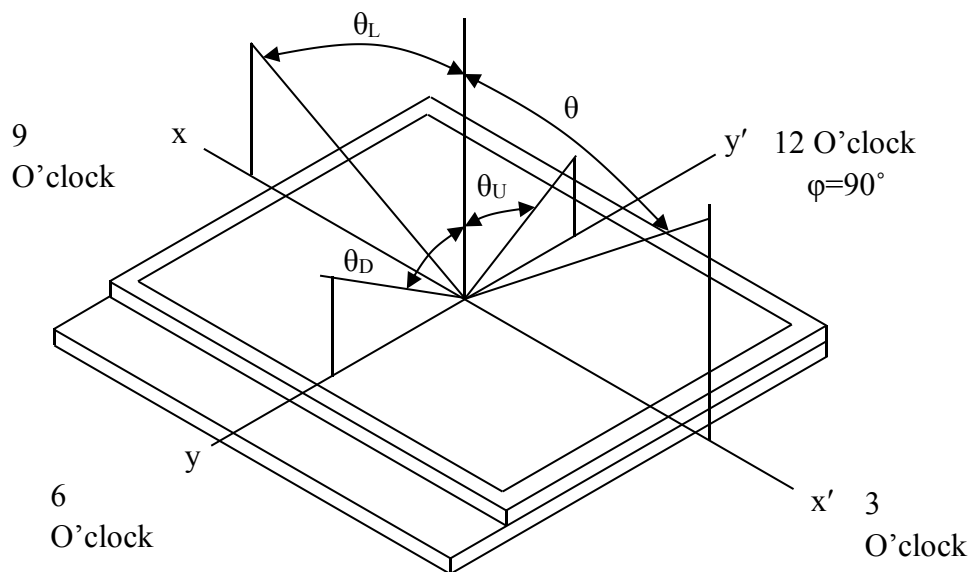


The spot locations for luminance measurement

(4) Definition of Response time: Sum of  $T_r$  and  $T_f$ .



(5) Definition of Viewing Angle: The viewing angle range that the  $CR \geq 10$ .

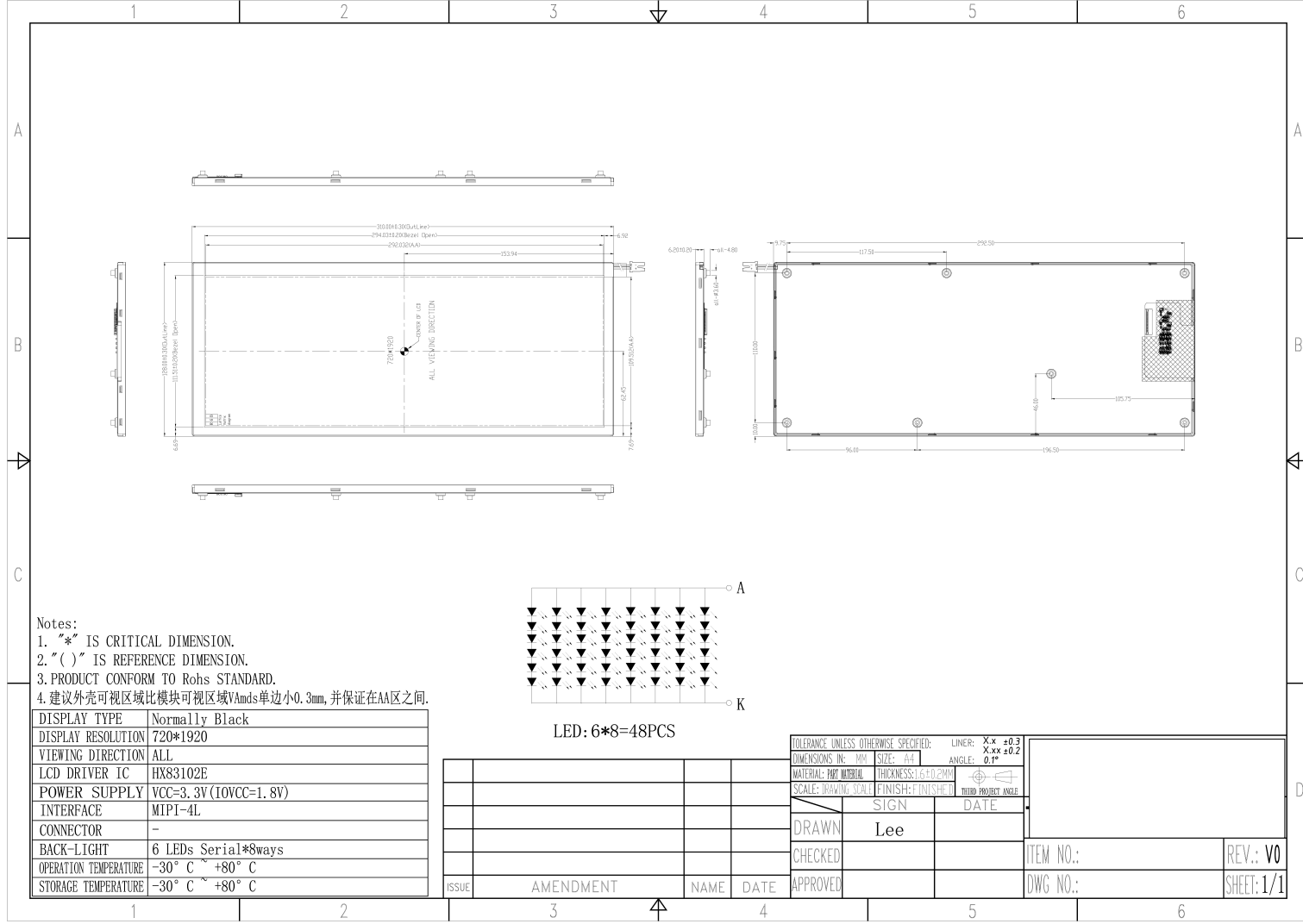


(6) Definition of Color Chromaticity (CIE 1931)

Color coordinate of white & red, green, blue at center point.

(7) The different Rubbing Direction will cause the different optima view direction.

# 4. MODULE OUTLINE DIMENSION



## 5. MODULE INTERFACE DESCRIPTION

Terminal No.	Symbol	I/O	Function
1	NC	-	No Connection
2	IOVCC	P	Power supply for digital circuits
3	IOVCC	P	Power supply for digital circuits
4		P	
5	RESET	I	Device reset signa
6	NC	-	No Connection
7	GND	P	Ground
8	D0N	I/O	High speed interface data differential signal input/output pins.
9	D0P	I/O	High speed interface data differential signal input/output pins.
10	GND	P	Ground
11	D1N	I	High speed interface data differential signal input pins
12	D1P	I	High speed interface data differential signal input pins
13	GND	P	Ground
14	CLKN	I	High speed interface CLOCK differential signal input pins.
15	CLKP	I	High speed interface CLOCK differential signal input pins.
16	GND	P	Ground
17	D2N	I	High speed interface data differential signal input pins
18	D2P	I	High speed interface data differential signal input pins
19	GND	P	Ground
20	D3N	I	High speed interface data differential signal input pins
21	D3P	I	High speed interface data differential signal input pins
22	GND	P	Ground
23	NC	-	No Connection
24	AVDD	-	+9V-12V
25	NC	-	No Connection
26	NC	-	No Connection
27	NC	-	No Connection
28	NC	-	No Connection
29	NC	-	No Connection
30	GND	P	Ground

I/O: I: input, O: output, P: power

**Remarks:**

- 1) Mating Connector: 089K60-000100-G2-R (STARCONN)
- 2) UPDN and SHLR control function

## 6. REFERENCE APPLICATION CIRCUIT

Please consult our technical department for detail information.

## 7. TIMINGS FOR MIPI Interface

### 7.1 Timing Waveform

Parameter	Symbol	Spec.			Unit	Condition
		Min.	Typ.	Max.		
Clock frequency	$R_{XFCLK}$	20	-	71	MHz	-
Input data skew margin	$T_{RSKM}$	500	-	-	pS	$ V_{ID} =400mV$ $R_{XVCM}=1.2V$ $R_{XFCLK}=71MHz$
Clock high time	$T_{LVCH}$	-	$4/(7 * R_{XFCLK})$	-	ns	-
Clock low time	$T_{LVCL}$	-	$3/(7 * R_{XFCLK})$	-	ns	-
PLL wake-up time	$T_{enPLL}$	-	-	150	$\mu s$	-

Table 10.2: LVDS mode AC electrical characteristics

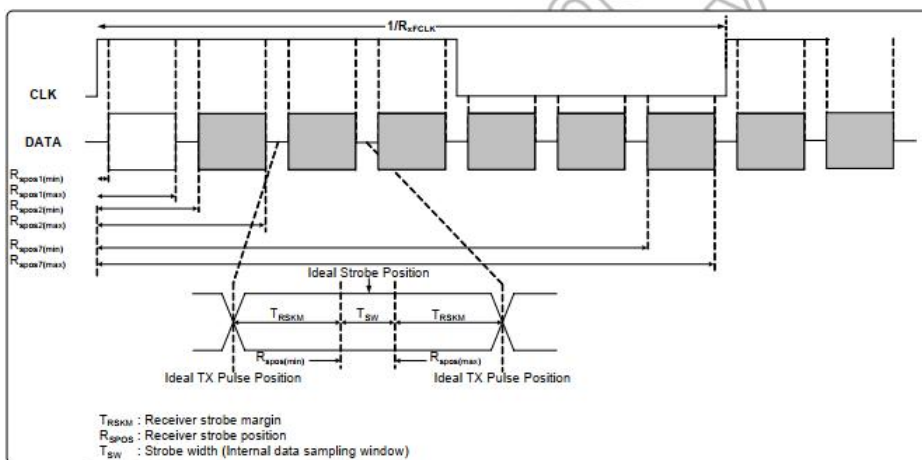
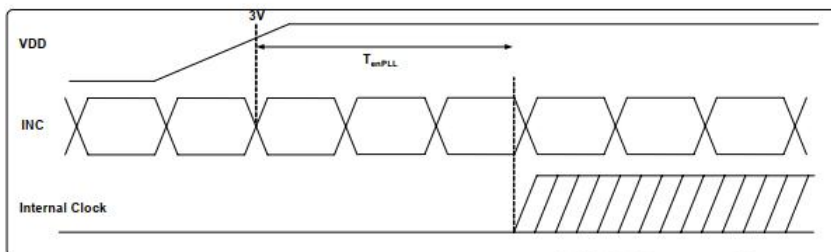
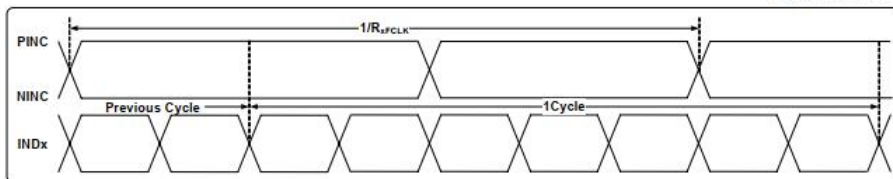


Figure 10.1: LVDS figure

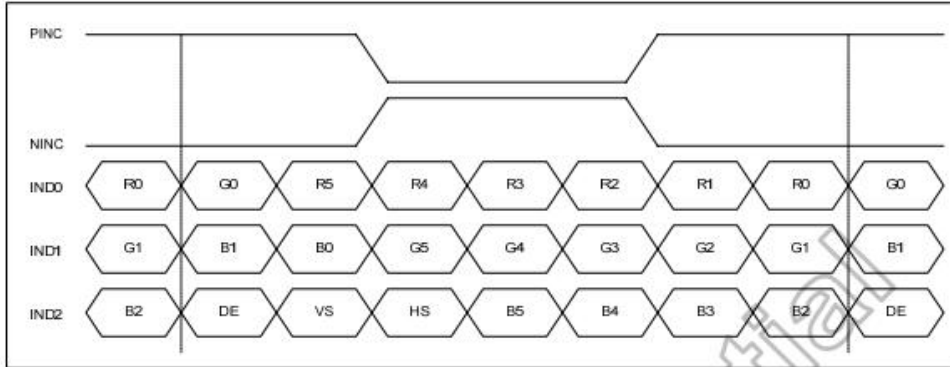


Figure 10.4: 6-bit LVDS input

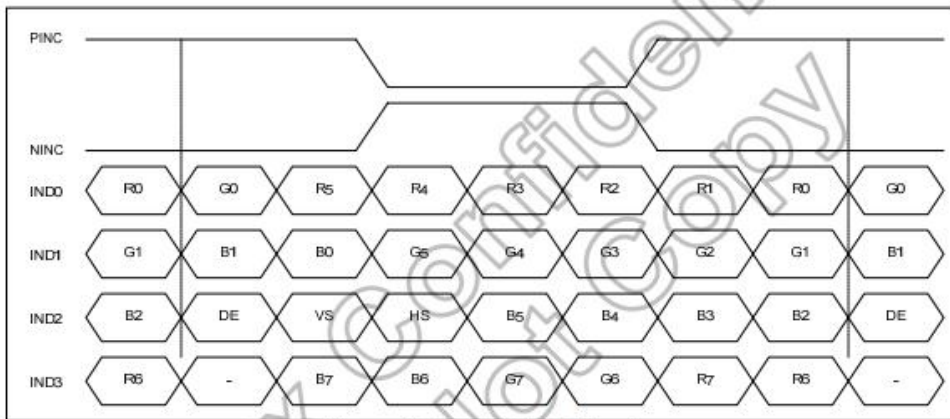


Figure 10.5: 8-bit LVDS Input

## 7.2 Power on/off

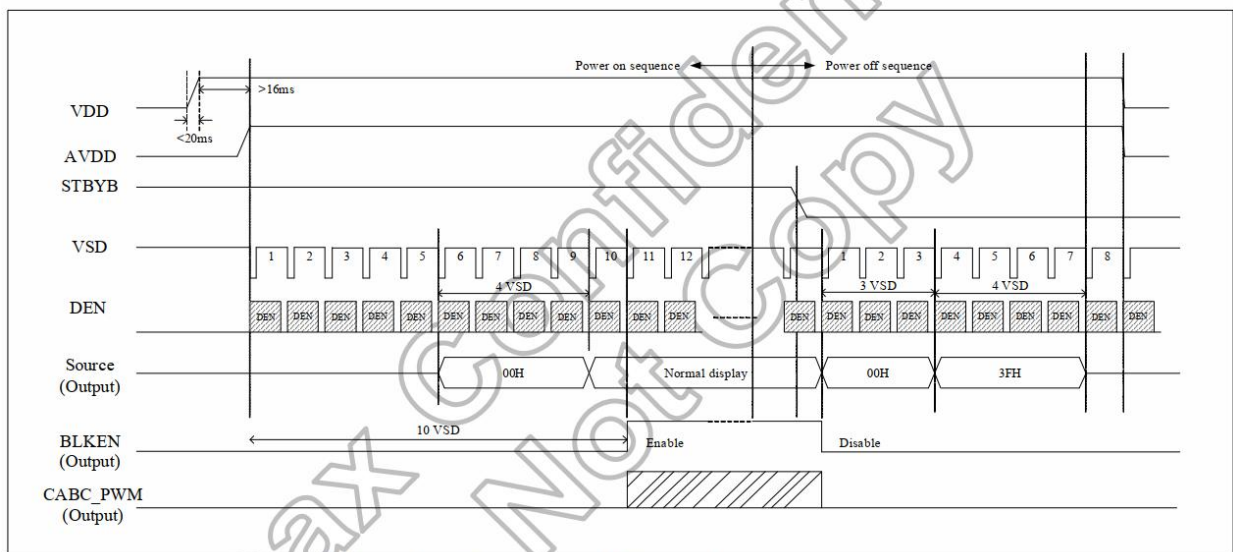


Figure 7.4 Power on/off Timing Sequence

## 8. RELIABILITY TEST CONDITIONS

No.	Test Item	Test Condition	Notes
1	High Temperature Storage	+80°C / 120H	Inspection after 2~4h storage at room temperature, the sample shall be free from defects: 1. Air bubble in the LCD; 2. Seal leak; 3. Non-display; 4. Missing segments; 5. Glass crack; 6. The surface shall be free from damage. 7. The electrical characteristics requirements shall be satisfied.
2	Low Temperature Storage	-30°C / 120H	
3	High Temperature Operating	+80°C / 120H	
4	Low Temperature Operating	-30°C / 120H	
5	Temperature Cycle	0±2°CΔ25°CΔ+50±2°C x 10cycles (30min) (5min) (30min)	
6	High Temperature /Humidity storage	50+5°C x 90%RH / 120H	
7	Vibration Test	Frequency: 10Hz~55Hz~10Hz Amplitude:1.5mm, 2 hours for each direction of X, Y, Z	
8	Packing Drop Test	Drop to the ground from 1m height, 1 corner, 3 edges, 6 surfaces.	
9	ESD test	Voltage:±8KV R: 330Ω C: 150pF Air discharge, 10time	
10	Image Sticking	25°C ±2°C Operation with test pattern sustained for 1 hrs(10x5). Change to gray pattern immediately. after 5 mins,the mura must be disappeared completely .	

### Remarks:

- (1) The test samples should be applied to only one test item.
- (2) Sample size for each test item is 5~10pcs.
- (3) For High Temperature/Humidity storage test, pure water (resistance>10MΩ) should be used.
- (4) In case of malfunction defect caused by ESD damage, if it would be recovered to normal state after resetting, it would be judge as a good part.
- (5) Failure judgment criterion: basic specification, electrical characteristic, mechanical characteristic, optical characteristic.

## 9. PACKING SPECIFICATION

